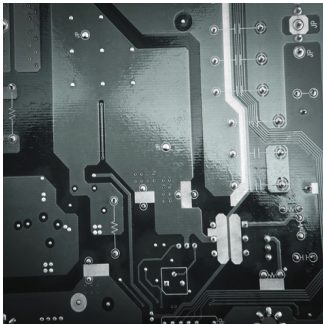




## 2SB886 Darlington BJT



Datasheet: [View](#)

Stock	
NEW JERSEY SEMICONDUCTOR	1400
SANYO	45

Trans Darlington PNP 100V 8A 3-Pin(3+Tab) TO-220AB

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Features	Values	Unit
Typical Current Gain Bandwidth	20	MHz
Type	PNP	
Number of Elements per Chip	1	
Minimum Operating Temperature	-55	°C
Minimum DC Current Gain	1500@4A@3V	
Maximum Operating Temperature	150	°C
Maximum Emitter Base Voltage	6	V
Maximum Continuous DC Collector Current	8	A
Maximum Collector Emitter Voltage	100	V
Maximum Collector Base Voltage	110	V
Maximum Base Emitter Saturation Voltage	2@8mA@4A	V
Configuration	Single	

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